

**AMENDMENTS TO THE ABSTRACT:**

Please amend the abstract as follows:

The present invention relates to measurement of conductivity, ~~particularly to the noncontact measurement of the conductivity using a microwave~~. A microwave oscillated by an oscillator [[(110)]] using a Gunn diode is applied through an isolator [[(120)]], a circulator [[(130)]], and a horn antenna [[(140)]] to a silicon wafer [[(150)]]. The isolator [[(120)]] is used for reducing the standing wave influencing the operation of the instrument. The reflected wave is received by the same horn antenna [[(140)]], detected by a detector [[(160)]] connected to the circulator [[(130)]]], and outputted in the form of a voltage. The detector [[(160)]] produces an output voltage proportional to the square of the amplitude of an electric field. Since the amplitude of the reflected wave from a silicon wafer [[(150)]] is proportional to the absolute value of the reflectance, the output voltage is also proportional to the square of the absolute value of the reflectance. The reflectance is in a certain relationship with the conductivity, the conductivity of the silicon wafer [[(150)]] can be determined.

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